

Catalog	Description	Actual amount
069UR3S1250B	PSC Square body fuse, 690V/1250A, Watts loss: 180W, Breaking capacity: 200kA, Indicator: Button Type	4,00
070GQCA0100F	PSC Square body fuse, 690V/100A, Watts loss: 23W, Breaking capacity: 200kA, Indicator: Flap Type	3,00
1606KL-04W-B50-L00	1606KL-04W-B50-L00	27,00
2408NL-04W-B50	2408NL-04W-B50	50,00
2410ML-05W-B50-D00	2410ML-05W-B50-D00	6,00
2410ML-05W-B50-D00	2410ML-05W-B50-D00	24,00
4715KL-05W-B40-P00	4715KL-05W-B40-P00	4,00
4715KL-07W-B30-P00	4715KL-07W-B30-P00	32,00
4715MS-12T-B5A-D00	4715MS-12T-B5A-D00	36,00
ALS31A102KE350	ALS31A102KE350	269,00
CLA100E1200HB	THYRISTOR-Phase Control, SCRs; 40A/1200V; T_VJM = 150°C; Phase Leg; ISOPLUS i4-PAC	20,00
CLA50E1200HB	THYRISTOR-Phase Control, SCRs; 40A/1200V; T_VJM = 150°C; Phase Leg; ISOPLUS i4-PAC	78,00
CLA80MT1200NHB	THYRISTOR Module-Triacs; -A/1200V; T_VJM = 150°C; Triac; TO-247AD	360,00
CM300DU-12NF	5th. Gen., IGBT Modul, 300A/600V, NF-Series, Dual, NF1	3,00
CM300HA-24H	3th Gen., IGBT, 300A/1200V, H-Series, Dual, STD Type-N/A	2,00
CM600DY-12NF	5th Gen., IGBT, 600A/600V, NF-Series, Dual, STD Type-11	5,00
CM750HG-130R	3rd. Ver., HV-IGBT, 750A/6500V, R-Series, 3in1, High-Iso. Type-11	2,00
CM75E3U-24H	3th Gen., IGBT, 75A/600V, U-Series, Brake chopper, STD Type-N/A	3,00
CS08-12io2	CS08-12io2	29,00
CS10-12ho1	CS10-12ho1	100,00
CS142-12io1	CS142-12io1	4,00
CS19-12ho1	THYRISTOR-Phase Control, SCRs; 20A/800V; T_VJM = 150°C; Single; TO-263 (D2 PAK)	34,00
CS23-12io2	THYRISTOR-Phase Control, SCRs; 25A/800V; T_VJM = 125°C; Single; TO-208AA (TO-48)	11,00
CS23-16io2	THYRISTOR-Phase Control, SCRs; 25A/1200V; T_VJM = 125°C; Single; TO-208AA (TO-48)	9,00
CS45-16io2	THYRISTOR-Phase Control, SCRs; 25A/1200V; T_VJM = 125°C; Single; TO-208AA (TO-48)	20,00
CS30-16io1	THYRISTOR-Phase Control, SCRs; 30A/1400V; T_VJM = 150°C; Single; TO-247	108,00
CS35-14io4	THYRISTOR-Phase Control, SCRs; 63A/1200V; T_VJM = 125°C; Single; TO-208AC (TO-65)	20,00
CS72-12io1	CS72-12io1	2,00
DH2X61-18A	DIODE-SONIC-FRD; 120A/1800V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	46,00
DH40-18A	DIODE-SONIC-FRD; 40A/1800V; T_VJM = 150°C; Single; TO-247AD	10,00
DHG100X1200NA	DIODE-SONIC-FRD; 100A/1200V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	20,00
DHG10I1200PM	DIODE-SONIC-FRD; 10A/1200V; T_VJM = 150°C; Single; TO-220ACFP	199,00
DHG30I1200HA	DIODE-SONIC-FRD; 30A/1200V; T_VJM = 150°C; Single; TO-247AD	6,00
DHG50X1200NA	DIODE-SONIC-FRD; 50A/1200V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	40,00
DHH55-36N1F	DIODE-SONIC-FRD; 60A/1800V; T_VJM = 150°C; Phase Leg; ISOPLUS i4-PAC	15,00
DPF240X400NA	DIODE-HiPerFRED 2nd Gen; 240A/400V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	200,00
DPG120C300QB	DIODE-HiPerFRED 2nd Gen; 120A/300V; T_VJM = 175°C; Common Cathode; TO-3P	15,00
DPG15I200PA	DIODE-HiPerFRED 2nd Gen; 15A/200V; T_VJM = 175°C; Single; TO-220AC	750,00
DPG30C200HB	DIODE-HiPerFRED 2nd Gen; 30A/200V; T_VJM = 175°C; Common Cathode; TO-247	10,00
DPG60C200QB	DIODE-HiPerFRED 2nd Gen; 60A/200V; T_VJM = 175°C; Common Cathode; TO-3P	11,00
DS75-12B	DIODE-Rectifier (Standard); 110A/1200V; T_VJM = 180°C; Single; DO-203AB (DO-5)	9,00
DSA110-18F	DSA110-18F	2,00

DSA1-18D	DIODE-Rectifier (Avalanche); 2,3A/1800V; T_VJM = 150°C; Single; Plastic Package	80,00
DSA17-12A	DIODE-Rectifier (Avalanche); 25A/1200V; T_VJM = 180°C; Single; DO-203AA (DO-4)	150,00
DSA17-16A	DIODE-Rectifier (Avalanche); 25A/1600V; T_VJM = 180°C; Single; DO-203AA (DO-4)	41,00
DSA2-16A	DIODE-Rectifier (Avalanche); 3,6A/1600V; T_VJM = 180°C; Single; Metal-Can	52,00
DSA240X200NA	DIODE-Silicon Schottky Gen 2; 240A/200V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	20,00
DSA300I100NA	DIODE-Silicon Schottky Gen 2; 300A/100V; T_VJM = 150°C; Single; SOT-227B (miniBLOC)	4,00
DSA300I45NA	DIODE-Silicon Schottky Gen 2; 300A/45V; T_VJM = 150°C; Single; SOT-227B (miniBLOC)	95,00
DSA30I150PA	DIODE-Silicon Schottky Gen 2; 30A/150V; T_VJM = 175°C; Single; TO-220AC	13,00
DSA35-16A	DIODE-Rectifier (Avalanche); 49A/1600V; T_VJM = 180°C; Single; DO-203AB (DO-5)	20,00
DSA75-16B	DIODE-Rectifier (Avalanche); 110A/1600V; T_VJM = 180°C; Single; DO-203AB (DO-5)	23,00
DSA9-12F	DIODE-Rectifier (Avalanche); 11A/1200V; T_VJM = 180°C; Single; DO-203AA (DO-4)	80,00
DSAI17-16A	DIODE-Rectifier (Avalanche); 25A/1600V; T_VJM = 180°C; Single; DO-203AA (DO-4)	16,00
DSAI17-18A	DIODE-Rectifier (Avalanche); 25A/1800V; T_VJM = 180°C; Single; DO-203AA (DO-4)	15,00
DSAI75-16B	DIODE-Rectifier (Avalanche); 110A/1600V; T_VJM = 180°C; Single; DO-203AB (DO-5)	15,00
DSDI60-18A	DIODE-SemiFast; -A/-V; T_VJM = -°C; Single; TO-247AD	16,00
DSEC120-12AK	DIODE-HiPerFRED; 120A/1200V; T_VJM = 175°C; Common Cathode; TO-264AA	4,00
DSEC240-04A	DIODE-HiPerFRED; 240A/400V; T_VJM = 150°C; Common Cathode; SOT-227B (miniBLOC)	17,00
DSEC30-12A	DIODE-HiPerFRED; 30A/1200V; T_VJM = 175°C; Common Cathode; TO-247AD	22,00
DSEC60-04A	DSEC60-04A	51,00
DSEC60-12A	DIODE-HiPerFRED; 60A/1200V; T_VJM = 175°C; Common Cathode; TO-247AD	36,00
DSEE15-12CC	DIODE-HiPerDYN FRED Phase-Leg; 15A/600V; T_VJM = 175°C; Phase Leg; ISOPLUS220	38,00
DSEE15-20CC	DSEE15-20CC	28,00
DSEE29-12CC	DIODE-HiPerDYN FRED Phase-Leg; 30A/600V; T_VJM = 175°C; Phase Leg; ISOPLUS220	50,00
DSEE55-24N1F	DIODE-HiPerDYN FRED Phase-Leg; 60A/1200V; T_VJM = 175°C; Phase Leg; ISOPLUS i4-PAC (3 - Lead)	39,00
DSEI110-06A	DSEI110-06A	54,00
DSEI120-06A	DIODE-FRED; 126A/600V; T_VJM = 150°C; Single; TO-247	54,00
DSEI120-12A	DIODE-FRED; 109A/1200V; T_VJM = 150°C; Single; TO-247	49,00
DSEI130-12A	DSEI130-12A	883,00
DSEI2X101-06A	DIODE-High Current FRED; 192A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	662,00
DSEI2X30-04C	DIODE-High Current FRED; 60A/400V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	10,00
DSEI2X30-12B	DIODE-High Current FRED; 60A/1000V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	25,00
DSEI2X31-06C	DIODE-High Current FRED; 60A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	35,00
DSEI2X31-10B	DIODE-High Current FRED; 60A/1000V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	138,00
DSEI2X31-12B	DIODE-High Current FRED; 56A/1200V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	41,00
DSEI2X61-02A	DIODE-High Current FRED; 120A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	53,00
DSEI2X61-12B	DIODE-High Current FRED; 120A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	230,00
DSEI2X61-06C	DIODE-High Current FRED; 120A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	5,00
DSEI30-06A	DIODE-FRED; 37A/600V; T_VJM = 150°C; Single; TO-247	240,00
DSEI30-12A	DIODE-FRED; 26A/1200V; T_VJM = 150°C; Single; TO-247	823,00
DSEI60-02A	DIODE-FRED; 69A/200V; T_VJM = 150°C; Single; TO-247	726,00
DSEI60-06A	DIODE-FRED; 60A/600V; T_VJM = 150°C; Single; TO-247	76,00
DSEI60-10A	DIODE-FRED; 60A/1000V; T_VJM = 150°C; Single; TO-247	125,00
DSEI60-12A	DIODE-FRED; 52A/1200V; T_VJM = 150°C; Single; TO-247	34,00
DSEI8-06AS	DIODE-FRED; 8A/600V; T_VJM = 150°C; Single; TO-263AB (D2 PAK)	10,00
DSEK60-02A	DIODE-FRED; 68A/200V; T_VJM = 150°C; Common Cathode; TO-247	24,00

DSEP12-12A	DIODE-HiPerFRED; 12A/1200V; T_VJM = 175°C; Single; TO-220AC	64,00
DSEP15-03A	DSEP15-03A	170,00
DSEP2X101-04A	DIODE-HiPerFRED; 200A/400V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	190,00
DSEP2X25-12C	DIODE-HiPerDYN FRED Single; 50A/1200V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	9,00
DSEP2X31-04A	DSEP2X31-04A	30,00
DSEP2X31-12A	DIODE-HiPerFRED; 60A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	76,00
DSEP2X31-06A	DIODE-HiPerFRED; 60A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	46,00
DSEP2X35-06C	DSEP2X35-06C	7,00
DSEP2X61-06A	DIODE-HiPerFRED; 120A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	40,00
DSEP2X61-12A	DIODE-HiPerFRED; 120A/1200V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	17,00
DSEP2X91-06A	DIODE-HiPerFRED; 180A/600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	4,00
DSEP30-03A	DSEP30-03A	134,00
DSEP30-12A	DIODE-HiPerFRED; 30A/1200V; T_VJM = 175°C; Single; TO-247AC	2,00
DSEP60-04A	DSEP60-04A	60,00
DSEP60-12A	DIODE-HiPerFRED; 60A/1200V; T_VJM = 175°C; Single; TO-247AC	36,00
DSEP8-06B	DIODE-HiPerFRED; 10A/600V; T_VJM = 175°C; Single; TO-220AC	200,00
DSI2X55-16A	DIODE-Rectifier (Standard); 120A/1600V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	60,00
DSI30-16A	DIODE-Rectifier (Standard); 30A/1600V; T_VJM = 175°C; Single; TO-220AC	40,00
DSP25-16A	DIODE-Rectifier (Standard); 25A/1600V; T_VJM = 175°C; Phase Leg; TO-247	78,00
DSP8-12A	DIODE-Rectifier (Standard); 8A/1200V; T_VJM = 175°C; Phase Leg; TO-220AB	240,00
DSS2X121-0045B	DIODE-Silicon Schottky; 240A/45V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	4,00
DSS2X41-01A	DIODE-Silicon Schottky; 80A/100V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	2,00
DSS2X61-0045A	DIODE-Silicon Schottky; 120A/45V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	9,00
DSS2X61-0045A	DIODE-Silicon Schottky; 120A/45V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	23,00
DSS2X61-01A	DIODE-Silicon Schottky; 120A/100V; T_VJM = 150°C; Dual; SOT-227B (miniBLOC)	9,00
DSSK30-01A	DIODE-Silicon Schottky; 30A/100V; T_VJM = 175°C; Common Cathode; TO-247	468,00
DSSK40-006B	DIODE-Silicon Schottky; 40A/60V; T_VJM = 150°C; Common Cathode; TO-247	9,00
DSSK48-003B	DIODE-Silicon Schottky; 50A/30V; T_VJM = 150°C; Common Cathode; TO-220AB	46,00
DSSK50-01A	DIODE-Silicon Schottky; 50A/100V; T_VJM = 175°C; Common Cathode; TO-247	13,00
DSSK60-0045A	DIODE-Silicon Schottky; 60A/45V; T_VJM = 175°C; Common Cathode; TO-247	22,00
DSSK80-003B	DIODE-Silicon Schottky; 80A/30V; T_VJM = 150°C; Common Cathode; TO-247	30,00
F1600MC120	F1600MC120	6,00
G1000NC450	Gate Turn Off Thyristors, 545A/4500V, Single, W36, Capsule type	6,00
IXBF32N300	IGBT-BiMOSFET Very High Voltage; 40A/3000V; V_CE(sat) = 3,2V; Copack (FRED); ISOPLUS i4-PAC	4,00
IXBH16N170	IGBT-High Voltage BiMOSFET; 40A/1700V; V_CE(sat) = 3,3V; Copack (FRED); TO-247	7,00
IXBH42N170	IGBT-High Voltage BiMOSFET; 80A/1700V; V_CE(sat) = 2,8V; Copack (FRED); TO-247	22,00
IXBH6N170	IGBT-High Voltage BiMOSFET; 10A/1700V; V_CE(sat) = 3,4V; Copack (FRED); TO-247	45,00
IXBOD1-06	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	34,00
IXBOD1-07	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	30,00
IXBOD1-10RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	146,00
IXBOD1-13RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	2,00
IXBOD1-14RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	4,00
IXBOD1-15RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	19,00
IXBOD1-16RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	10,00
IXBOD1-18RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	9,00

IXBOD1-20RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	8,00
IXBOD1-19RD	PROTECTION DEVICES- BOD Gen. 1; 15A/700V; dv/dt = >1000V/μs ;Single; FP-Case (oilproof)	9,00
IXBOD1-22RD	PROTECTION DEVICES- BOD Gen. 1; 15A/2200V; dv/dt = >2000V/μs ;Single; BOD-Package	10,00
IXBOD1-23RD	PROTECTION DEVICES- BOD Gen. 1; 15A/2200V; dv/dt = >2000V/μs ;Single; BOD-Package	6,00
IXBOD1-32RD	PROTECTION DEVICES- BOD Gen. 1; 15A/2200V; dv/dt = >2000V/μs ;Single; BOD-Package	19,00
IXBOD1-23R	PROTECTION DEVICES- BOD Gen. 1; 15A/2300V; dv/dt = >2000V/μs ;Single; BOD-Package	10,00
IXCP20M45	HV CURRENT REGULATORS-Non-Switchable; 20A/450V; Single; TO-220AB	10,00
IXCY10M90S	HV CURRENT REGULATORS-Switchable; 100A/900V; Single; TO-252AA (D PAK)	72,00
IXDD408YI	IXDD408YI	30,00
IXDD409YI	IXDD409YI	75,00
IXDD609PI	IXDD609PI	50,00
IXDD609SI	IXDD609SI	100,00
IXDD614SI	IXDD614SI	100,00
IXDD614YI	IXDD614YI	5,00
IXDF402SI	IXDF402SI	80,00
IXDF404SI	IXDF404SI	193,00
IXDH35N60BD1	IGBT-NPT Discrete; 60A/600V; V_CE(sat) = 2,7V; Copack (FRED); TO-247	6,00
IXDI430MCI	IXDI430MCI	705,00
IXDI430YI	IXDI430YI	242,00
IXDN402PI	IXDN402PI	10,00
IXDN404SI	IXDN404SI	149,00
IXDN409PI	IXDN409PI	190,00
IXDN430CI	IXDN430CI	21,00
IXDN430YI	IXDN430YI	90,00
IXDN75N170	IGBT-NPT Discrete; 150A/1200V; V_CE(sat) = 2,7V; Single; SOT-227B (miniBLOC)	10,00
IXDN75N120	IGBT-NPT Discrete; 150A/1200V; V_CE(sat) = 2,7V; Single; SOT-227B (miniBLOC)	5,00
IXDP610PI	IXDP610PI	15,00
IXDP630PI	IXDP630PI	82,00
IXEN60N-D1	IXEN60N-D1	2,00
IXEN60N120	IXEN60N120	31,00
IXFB100N50P	MOSFET-Polar HiPerFETs; 100A/500V; R_DS(on) = 0,049Ω; Single; PLUS264; N-Channel	23,00
IXFB38N100Q2	MOSFET-Q2-Class HiPerFETs; 38A/1000V; R_DS(on) = 0,25Ω; Single; PLUS264; N-Channel	17,00
IXFB90N85X	MOSFET-850V X-Class HiPerFET™; 90A/850V; R_DS(on) = 0,041Ω; Single; PLUS264; N-Channel	25,00
IXFE48N50Q	MOSFET-Q-Class HiPerFETs; 41A/500V; R_DS(on) = 0,11Ω; Single; ISOPLUS227; N-Channel	17,00
IXFH12N120P	MOSFET-Polar HiPerFETs; 12A/1200V; R_DS(on) = 1,35Ω; Single; TO-247; N-Channel	15,00
IXFH13N80Q	MOSFET-Q-Class HiPerFETs; 13A/800V; R_DS(on) = 0,7Ω; Single; TO-247; N-Channel	22,00
IXFH15N100	MOSFET-HiPerFETs ; 15A/1000V; R_DS(on) = 0,7Ω; Single; TO-247; N-Channel	10,00
IXFH15N80Q	MOSFET-Q-Class HiPerFETs; 15A/800V; R_DS(on) = 0,6Ω; Single; TO-247; N-Channel	10,00
IXFH20N60Q	MOSFET-Q-Class HiPerFETs; 20A/600V; R_DS(on) = 0,35Ω; Single; TO-247; N-Channel	2,00
IXFH20N80P	MOSFET-Polar HiPerFETs; 20A/800V; R_DS(on) = 0,52Ω; Single; TO-247; N-Channel	60,00
IXFH21N50Q	MOSFET-Q-Class HiPerFETs; 21A/500V; R_DS(on) = 0,25Ω; Single; TO-247; N-Channel	4,00
IXFH23N80Q	MOSFET-Q-Class HiPerFETs; 23A/800V; R_DS(on) = 0,42Ω; Single; TO-247; N-Channel	10,00
IXFH26N50Q	MOSFET-Q-Class HiPerFETs; 26A/500V; R_DS(on) = 0,2Ω; Single; TO-247; N-Channel	70,00
IXFH26N60Q	MOSFET-Q-Class HiPerFETs; 28A/600V; R_DS(on) = 0,25Ω; Single; TO-247; N-Channel	24,00
IXFH60N25Q	MOSFET-Q-Class HiPerFETs; 60A/250V; R_DS(on) = 0,047Ω; Single; TO-247; N-Channel	30,00

IXFH69N30P	MOSFET-Polar HiPerFETs; 69A/300V; R_DS(on) = 0,049Ω; Single; TO-247; N-Channel	30,00
IXFH8N80	MOSFET-HiPerFETs ; 8A/800V; R_DS(on) = 1,1Ω; Single; TO-247; N-Channel	22,00
IXFK140N30P	MOSFET-Polar HiPerFETs; 140A/300V; R_DS(on) = 0,024Ω; Single; TO-264; N-Channel	17,00
IXFK30N100Q2	MOSFET-Q2-Class HiPerFETs; 30A/1000V; R_DS(on) = 0,4Ω; Single; TO-264; N-Channel	25,00
IXFK32M50Q	IXFK32M50Q	25,00
IXFK44N50P	MOSFET-Polar HiPerFETs; 44A/500V; R_DS(on) = 0,14Ω; Single; TO-264; N-Channel	54,00
IXFK44N60	MOSFET-HiPerFETs ; 44A/600V; R_DS(on) = 0,13Ω; Single; TO-264; N-Channel	42,00
IXFK55N50	MOSFET-Polar HiPerFETs; 55A/500V; R_DS(on) = 0,065Ω; Single; TO-264; N-Channel	2,00
IXFK180N10	MOSFET-Polar HiPerFETs; 180A/500V; R_DS(on) = 0,065Ω; Single; TO-264; N-Channel	22,00
IXFK80N50P	MOSFET-Polar HiPerFETs; 80A/500V; R_DS(on) = 0,065Ω; Single; TO-264; N-Channel	24,00
IXFN100N25	MOSFET-HiPerFETs ; 100A/250V; R_DS(on) = 0,027Ω; Single; SOT-227B (miniBLOC); N-Channel	12,00
IXFN102N30P	MOSFET-Polar HiPerFETs; 86A/300V; R_DS(on) = 0,033Ω; Single; SOT-227B (miniBLOC); N-Channel	10,00
IXFN130N30	MOSFET-HiPerFETs ; 130A/300V; R_DS(on) = 0,018Ω; Single; SOT-227B (miniBLOC); N-Channel	10,00
IXFN15N15	MOSFET-HiPerFETs ; 15A/150V; R_DS(on) = 0,0125Ω; Single; SOT-227B (miniBLOC); N-Channel	5,00
IXFN180N15P	MOSFET-Polar HiPerFETs; 180A/150V; R_DS(on) = 0,011Ω; Single; SOT-227B (miniBLOC); N-Channel	35,00
IXFN120N20P	MOSFET-Polar HiPerFETs; 120A/150V; R_DS(on) = 0,011Ω; Single; SOT-227B (miniBLOC); N-Channel	1,00
IXFN180N20	MOSFET-HiPerFETs ; 180A/200V; R_DS(on) = 0,0125Ω; Single; SOT-227B (miniBLOC); N-Channel	49,00
IXFN200N10P	MOSFET-Polar HiPerFETs; 200A/100V; R_DS(on) = 0,0075Ω; Single; SOT-227B (miniBLOC); N-Channel	50,00
IXFN340N06	MOSFET-HiPerFETs ; 340A/60V; R_DS(on) = 0,003Ω; Single; SOT-227B (miniBLOC); N-Channel	95,00
IXFN340N07	MOSFET-HiPerFETs ; 340A/70V; R_DS(on) = 0,004Ω; Single; SOT-227B (miniBLOC); N-Channel	27,00
IXFN34N80	MOSFET-HiPerFETs ; 34A/800V; R_DS(on) = 0,24Ω; Single; SOT-227B (miniBLOC); N-Channel	8,00
IXFN360N10T	MOSFET-Trench HiperFETs; 360A/100V; R_DS(on) = 0,0026Ω; Single; SOT-227B (miniBLOC); N-Channel	50,00
IXFN38N150	MOSFET-Polar HiPerFETs; 38A/1000V; R_DS(on) = 0,21Ω; Single; SOT-227B (miniBLOC); N-Channel	6,00
IXFN38N100Q2	MOSFET-Q2-Class HiPerFETs; 38A/1000V; R_DS(on) = 0,25Ω; Single; SOT-227B (miniBLOC); N-Channel	10,00
IXFN420N10T	MOSFET-Trench HiperFETs; 420A/100V; R_DS(on) = 0,0023Ω; Single; SOT-227B (miniBLOC); N-Channel	40,00
IXFN44N80	MOSFET-HiPerFETs ; 44A/800V; R_DS(on) = 0,165Ω; Single; SOT-227B (miniBLOC); N-Channel	15,00
IXFN50N120SIC	MOSFET-TrenchT2 HiperFETs; 480A/75V; R_DS(on) = 0,0019Ω; Single; SOT-227B (miniBLOC); N-Channel	15,00
IXFN520N075T2	MOSFET-TrenchT2 HiperFETs; 480A/75V; R_DS(on) = 0,0019Ω; Single; SOT-227B (miniBLOC); N-Channel	10,00
IXFN60N80P	MOSFET-Polar HiPerFETs; 53A/800V; R_DS(on) = 0,14Ω; Single; SOT-227B (miniBLOC); N-Channel	20,00
IXFN64N50P	MOSFET-Polar HiPerFETs; 50A/500V; R_DS(on) = 0,085Ω; Single; SOT-227B (miniBLOC); N-Channel	18,00
IXFN280N07	MOSFET-Polar HiPerFETs; 280A/600V; R_DS(on) = 0,075Ω; Single; SOT-227B (miniBLOC); N-Channel	200,00
IXFM21N50Q	MOSFET-Polar HiPerFETs; 21A/600V; R_DS(on) = 0,075Ω; Single; SOT-227B (miniBLOC); N-Channel	4,00
IXFN82N60P	MOSFET-Polar HiPerFETs; 72A/600V; R_DS(on) = 0,075Ω; Single; SOT-227B (miniBLOC); N-Channel	25,00
IXFP6N120P	MOSFET-Polar HiPerFETs; 6A/1200V; R_DS(on) = 2,75Ω; Single; TO-220; N-Channel	20,00
IXFR75N10Q	IXFR75N10Q	26,00
IXFX120N25P	MOSFET-Polar HiPerFETs; 120A/250V; R_DS(on) = 0,024Ω; Single; PLUS247; N-Channel	21,00
IXFX48N50Q	MOSFET-Q-Class HiPerFETs; 48A/500V; R_DS(on) = 0,1Ω; Single; PLUS247; N-Channel	10,00
IXFX98N50P3	MOSFET-Polar3 HiPerFETs; 98A/500V; R_DS(on) = 0,05Ω; Single; PLUS247; N-Channel	4,00
IXFZ520N075T2	MOSFET-TrenchT2 HiperFETs; 420A/75V; R_DS(on) = 0,0016Ω; Single; DE475; N-Channel	29,00
IXGH10N170A	IGBT-High Voltage NPT; 12A/1700V; V_CE(sat) = 4V; Single; TO-247 AD	67,00
IXGH15N120CD1	IGBT-PT Frequency >40khz; 30A/1200V; V_CE(sat) = 3,8V; Copack (FRED); TO-247	51,00
IXGH16N170A	IGBT-High Voltage NPT; 20A/1700V; V_CE(sat) = 4V; Single; TO-268 (D3Pak)	114,00
IXGH16N170AH1	IGBT-High Voltage NPT; 75A/1700V; V_CE(sat) = 3,3V; Copack (FRED); PLUS247	15,00
IXGH20N120B	IGBT-PT Frequency 15khz-40khz; 40A/1200V; V_CE(sat) = 3,4V; Single; TO-247	101,00
IXGH25N120	IGBT-PT Frequency DC-15khz; 50A/1200V; V_CE(sat) = 3V; Single; TO-247	14,00

IXGH28N120B	IGBT-PT Frequency 15khz-40khz; 50A/1200V; V_CE(sat) = 3,5V; Single; TO-247	41,00
IXGH32N170A	IGBT-PT Frequency 15khz-40khz; 50A/1200V; V_CE(sat) = 3,5V; Single; TO-247	1,00
IXGH30N120B3D1	IGBT-PT Frequency 15kHz-40kHz w/Diode; 50A/1200V; V_CE(sat) = 3,5V; Copack (FRED); TO-247	36,00
IXGH40N120C3D1	IGBT-PT Frequency >40khz; 75A/1200V; V_CE(sat) = 4,4V; Copack (FRED); TO-247	31,00
IXGH40N60C2	IGBT-PT Frequency >40khz; 75A/600V; V_CE(sat) = 2,7V; Single; TO-247	66,00
IXGH40N60C2D1	IGBT-PT Frequency >40khz; 75A/600V; V_CE(sat) = 2,7V; Copack (FRED); TO-247	98,00
IXGH64N60A3	IGBT-PT Frequency DC-15khz; -A/600V; V_CE(sat) = 1,35V; Single; TO-247	60,00
IXGH85N30C3	IGBT-PT Frequency >40khz; 420A/300V; V_CE(sat) = 1,9V; Single; TO-247	120,00
IXGN200N60B	IGBT-PT Frequency 15khz-40khz; 200A/600V; V_CE(sat) = 2,1V; Single; SOT-227B (miniBLOC)	26,00
IXGN50N120C3H1	IGBT-PT Frequency >40khz; 95A/1200V; V_CE(sat) = 4,2V; Copack (FRED); SOT-227B (miniBLOC)	12,00
IXGN50N60B	IGBT-PT Frequency 15khz-40khz; 75A/600V; V_CE(sat) = 2,3V; Single; SOT-227B (miniBLOC)	47,00
IXGN60N60C2D1	IGBT-PT Frequency >40khz; 75A/600V; V_CE(sat) = 2,5V; Copack (FRED); SOT-227B (miniBLOC)	37,00
IXGP15N120B	IGBT-PT Frequency 15khz-40khz; 30A/1200V; V_CE(sat) = 3,2V; Single; TO-220	15,00
IXGP20N100	IGBT-PT Frequency DC-15khz; 40A/1000V; V_CE(sat) = 3V; Single; TO-220	22,00
IXGP24N60C4D1	IGBT-PT Frequency >40khz; 56A/600V; V_CE(sat) = 2,7V; Copack (FRED); TO-220	222,00
IXGR11-P7	IXGR11-P7	9,00
IXGR24N120C3D1	IGBT-PT Frequency >40khz; 48A/1200V; V_CE(sat) = 4,2V; Copack (FRED); ISOLPUS-247	105,00
IXGR40N60C2D1	IGBT-PT Frequency >40khz; 56A/600V; V_CE(sat) = 2,7V; Copack (FRED); ISOLPUS-247	1,00
IXGR72N60B3H1	IGBT-PT Frequency 15kHz-40kHz w/Diode; 80A/600V; V_CE(sat) = 1,8V; Copack (FRED); ISOPLUS247	30,00
IXGT32N170	IGBT-High Voltage NPT; 24A/1700V; V_CE(sat) = 6V; Single; TO-247	16,00
IXHQ100S1-16	IXHQ100S1-16	15,00
IXKH47N60C	MOSFET-C3-Class COOLMOS; 47A/600V; R_DS(on) = 0,07Ω; Single; TO-247; N-Channel	30,00
IXKN40N60C	MOSFET-C3-Class COOLMOS; 40A/600V; R_DS(on) = 0,07Ω; Single; SOT-227B (miniBLOC); N-Channel	
IXRH40X120	IXRH40X120	25,00
IXSH24N60AU1	IGBT-NPT S-Series; 48A/600V; V_CE(sat) = 2V; Copack (FRED); TO-247	20,00
IXSX35N120AU1	IGBT-PT S-Series; 70A/1200V; V_CE(sat) = 3,6V; Copack (FRED); TO-264	16,00
IXTA1N120P	MOSFET-Polar; 1A/1200V; R_DS(on) = 20Ω; Single; TO-263; N-Channel	800,00
IXTB62N52L	MOSFET-Linear; 62A/500V; R_DS(on) = 0,1Ω; Single; PLUS264; N-Channel	31,00
IXTH12N120	MOSFET-High Voltage; 12A/1200V; R_DS(on) = 1,4Ω; Single; TO-247; N-Channel	5,00
IXTH13N110	MOSFET-High Voltage; 13A/1100V; R_DS(on) = 0,92Ω; Single; TO-247; N-Channel	4,00
IXTH14N100	MOSFET-High Voltage; 14A/1000V; R_DS(on) = 0,82Ω; Single; TO-247; N-Channel	58,00
IXTH48P20P	MOSFET-Polar P; -48A/-200V; R_DS(on) = 0,085Ω; Single; TO-247; P-Channel	103,00
IXTH280N055T	MOSFET-Polar P; -48A/-200V; R_DS(on) = 0,085Ω; Single; TO-247; P-Channel	30,00
IXTH60N20L2	MOSFET-L2 Linear; 60A/200V; R_DS(on) = 0,045Ω; Single; TO-247; N-Channel	81,00
IXTH1N250	MOSFET-L2 Linear; 60A/200V; R_DS(on) = 0,045Ω; Single; TO-247; N-Channel	12,00
IXI85-8SI	IXI85-8SI	194,00
IXTH6N120	MOSFET-High Voltage; 6A/1200V; R_DS(on) = 2,4Ω; Single; TO-247; N-Channel	29,00
IXTK110N20L2	MOSFET-L2 Linear; 110A/200V; R_DS(on) = 0,024Ω; Single; TO-264; N-Channel	40,00
IXTK120N20P	MOSFET-L2 Linear; 120A/200V; R_DS(on) = 0,024Ω; Single; TO-264; N-Channel	45,00
IXTK140N30P	MOSFET-Polar; 140A/300V; R_DS(on) = 0,24Ω; Single; TO-264; N-Channel	15,00
IXTK32P60P	MOSFET-Polar P; -32A/-600V; R_DS(on) = 0,35Ω; Single; TO-264; P-Channel	23,00
IXTK40P50P	MOSFET-Polar P; -40A/-500V; R_DS(on) = 0,23Ω; Single; TO-264; P-Channel	28,00
IXTK90P20P	MOSFET-Polar P; -90A/-200V; R_DS(on) = 0,044Ω; Single; TO-264; P-Channel	34,00
IXTN200N10T	MOSFET-Trench; 200A/100V; R_DS(on) = 0,0055Ω; Single; SOT-227B (miniBLOC); N-Channel	13,00
IXTN320N10T	MOSFET-Trench; 320A/100V; R_DS(on) = 0,0032Ω; Dual; SOT-227B (miniBLOC); N-Channel	31,00

IXTN550N055T2	MOSFET-TrenchT2 MOSFETs; 550A/55V; R_DS(on) = 0,0013Ω; Single; SOT-227B (miniBLOC); N-Channel	32,00
IXTP32P05T	MOSFET-TrenchT2 MOSFETs; 32A/55V; R_DS(on) = 0,0013Ω; Single; SOT-227B (miniBLO)	30,00
IXTP01N100D	MOSFET-Depletion Mode; 0,1A/1000V; R_DS(on) = 80Ω; Single; TO-220; N-Channel	35,00
IXTP3N120	MOSFET-High Voltage; 3A/1200V; R_DS(on) = 4,5Ω; Single; TO-220; N-Channel	335,00
IXTP50N085T	MOSFET-Trench; 50A/85V; R_DS(on) = 0,023Ω; Single; TO-220; N-Channel	30,00
IXTQ44N50P	MOSFET-Polar; 44A/500V; R_DS(on) = 0,14Ω; Single; TO-3P; N-Channel	48,00
IXTQ64N25P	MOSFET-Polar; 64A/250V; R_DS(on) = 0,049Ω; Single; TO-3P; N-Channel	10,00
IXTQ69N30P	MOSFET-Polar; 69A/300V; R_DS(on) = 0,049Ω; Single; TO-3P; N-Channel	60,00
IXTQ74N200	IXTQ74N200	8,00
IXTX2N100P	IXTX2N100P	125,00
IXTQ96N20P	MOSFET-Polar; 96A/200V; R_DS(on) = 0,024Ω; Single; TO-3P; N-Channel	30,00
IXTX5N250	MOSFET-Very High Voltage; 5A/2500V; R_DS(on) = 8,8Ω; Single; PLUS247; N-Channel	20,00
IXTX90P20P	MOSFET-Polar P; -90A/200V; R_DS(on) = 0,044Ω; Single; PLUS247; P-Channel	57,00
IXTY01N100D	MOSFET-Depletion Mode; 0,1A/1000V; R_DS(on) = 80Ω; Single; TO-252 AA (D PAK); N-Channel	320,00
IXTY2N100P	MOSFET-Polar; 2A/1000V; R_DS(on) = 7,5Ω; Single; TO-252 AA (D PAK); N-Channel	125,00
IXXR100N50B3H1	IXXR100N50B3H1	13,00
IXYH20N120C3D1	IGBT-1200V XPT B3 GenX3; 43A/1200V; V_CE(sat) = 1,8V; Half Bridge; SMPD	25,00
IXYH50N120C3D1	IGBT-1200V XPT B3 GenX3; 36A/1200V; V_CE(sat) = 4V; Copack (FRED); TO-268 (HV)	20,00
IXYN100N120C3H1	IGBT-1200V XPT B3 GenX3; 66A/1200V; V_CE(sat) = 3,3V; Copack (FRED); TO-247	100,00
IXYX100N120B3	IGBT-1200V XPT B3 GenX3; 225A/1200V; V_CE(sat) = 2,6V; Single; PLUS247	10,00
KHR2-T227 50R	KHR2-T227 50R	200,00
MCC161-22io1	THYRISTOR Module-Dual Thyristor; 165A/2200V; T_VJM = 125°C; Phase Leg; Y4-M6 (+ Kelvin contact)	4,00
MCC162-16io1	THYRISTOR Module-Dual Thyristor; 181A/1600V; T_VJM = 125°C; Phase Leg; Y4-M6 (+ Kelvin contact)	3,00
MCC132-16io1	THYRISTOR Module-Dual Thyristor; 181A/1600V; T_VJM = 125°C; Phase Leg; Y4-M6 (+ Kelvin contact)	1,00
MCC21-14io8B	THYRISTOR Module-Dual Thyristor; 21A/1400V; T_VJM = 125°C; Phase Leg; TO-240 AA (w/o Kelvin contact)	10,00
MCC220-16io1	THYRISTOR Module-Dual Thyristor; 250A/1600V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	10,00
MCC200-14io1	THYRISTOR Module-Dual Thyristor; 290A/1600V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	4,00
MCC250-18io1	THYRISTOR Module-Dual Thyristor; 290A/1600V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	1,00
MCC250-16io1	THYRISTOR Module-Dual Thyristor; 290A/1600V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	15,00
MCC255-16io1	THYRISTOR Module-Dual Thyristor; 290A/1600V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	1,00
MCC26-12io1B	THYRISTOR Module-Dual Thyristor; 27A/1600V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	19,00
MCC310-18io1	THYRISTOR Module-Dual Thyristor; 320A/1800V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	12,00
MCC312-16io1	THYRISTOR Module-Dual Thyristor; 320A/1800V; T_VJM = 140°C; Phase Leg; Y2-DCB (+ Kelvin contact)	1,00
MCC312-18io1	THYRISTOR Module-Dual Thyristor; 320A/1800V; T_VJM = 140°C; Phase Leg; Y1-CU (+ Kelvin contact)	2,00
MCC44-18io1B	THYRISTOR Module-Dual Thyristor; 49A/1800V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	2,00
MCC501-16io2	Dual Thyristor Module, 503A/1600V, MC2, W74, Standard Type	4,00
MCC56-16io1B	THYRISTOR Module-Dual Thyristor; 60A/1600V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	33,00
MCC56-18io1B	THYRISTOR Module-Dual Thyristor; 60A/1800V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	30,00
MCC94-22io1B	THYRISTOR Module-Dual Thyristor; 104A/2200V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	6,00
MCC95-14io1B	THYRISTOR Module-Dual Thyristor; 116A/1600V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	2,00
MCC95-16io1B	THYRISTOR Module-Dual Thyristor; 116A/1600V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	21,00
MCC95-18io1B	THYRISTOR Module-Dual Thyristor; 116A/1800V; T_VJM = 125°C; Phase Leg; TO-240 AA (+ Kelvin contact)	16,00
MCD26-16io8B	DIODE/THYRISTOR Module-Thyristor/Diode ; 27A/1600V; T_VJM = 125°C; Phase Leg; TO-240 AA (w/o Kelvin	3,00
MCD95-12io8B	DIODE/THYRISTOR Module-Thyristor/Diode ; 116A/1200V; T_VJM = 125°C; Phase Leg; TO-240 AA (w/o Kelvin	11,00
MCD95-16io8B	DIODE/THYRISTOR Module-Thyristor/Diode ; 116A/1600V; T_VJM = 125°C; Phase Leg; TO-240 AA (w/o Kelvin	6,00

MCMA700P1800CA	THYRISTOR Module-Dual Thyristor; 700A/1800V; T_VJM = 140°C; Phase Leg; ComPack	3,00
MCO50-16io1	THYRISTOR Module-Single Thyristor; 560A/1400V; T_VJM = 140°C; Single; Y1-CU (+ Kelvin contact)	1,00
MCO500-14io1	THYRISTOR Module-Single Thyristor; 560A/1400V; T_VJM = 140°C; Single; Y1-CU (+ Kelvin contact)	4,00
MDD142-12N1	DIODE Module-Dual Diode; 165A/1200V; T_VJM = 150°C; Phase Leg; Y4-M6 (w/o pin 4, 5, 6 & 7)	6,00
MDD172-12N1	DIODE Module-Dual Diode; 190A/1200V; T_VJM = 150°C; Phase Leg; Y4-M6 (w/o pin 4, 5, 6 & 7)	48,00
MDD200-16N1	DIODE Module-Dual Diode; 224A/1600V; T_VJM = 150°C; Phase Leg; Y4-M6 (w/o pin 4, 5, 6 & 7)	16,00
MDD220-08N1	DIODE Module-Dual Diode; 224A/1600V; T_VJM = 150°C; Phase Leg; Y4-M6 (w/o pin 4, 5, 6 & 7)	3,00
MDD26-16N1B	DIODE Module-Dual Diode; 36A/1600V; T_VJM = 150°C; Phase Leg; TO-240 AA (w/o pin 4, 5, 6 & 7)	16,00
MDD310-12N1	DIODE Module-Dual Diode; 300A/1200V; T_VJM = 150°C; Phase Leg; Y2-DCB (w/o pin 4, 5, 6 & 7)	2,00
MDD310-16N1	DIODE Module-Dual Diode; 300A/1600V; T_VJM = 150°C; Phase Leg; Y2-DCB (w/o pin 4, 5, 6 & 7)	34,00
MDD310-20N1	DIODE Module-Dual Diode; 300A/2000V; T_VJM = 150°C; Phase Leg; Y2-DCB (w/o pin 4, 5, 6 & 7)	2,00
MDD312-12N1	DIODE Module-Dual Diode; 310A/1200V; T_VJM = 150°C; Phase Leg; Y1-CU (w/o pin 4, 5, 6 & 7)	3,00
MDD312-18N1	DIODE Module-Dual Diode; 310A/1800V; T_VJM = 150°C; Phase Leg; Y1-CU (w/o pin 4, 5, 6 & 7)	6,00
MDD44-18N1B	DIODE Module-Dual Diode; 59A/1800V; T_VJM = 150°C; Phase Leg; TO-240 AA (w/o pin 4, 5, 6 & 7)	7,00
MDD56-08N1B	DIODE Module-Dual Diode; 71A/800V; T_VJM = 150°C; Phase Leg; TO-240 AA (w/o pin 4, 5, 6 & 7)	5,00
MDD56-16N1B	DIODE Module-Dual Diode; 71A/1600V; T_VJM = 150°C; Phase Leg; TO-240 AA (w/o pin 4, 5, 6 & 7)	33,00
MDD95-16N1B	DIODE Module-Dual Diode; 120A/1600V; T_VJM = 150°C; Phase Leg; TO-240 AA (w/o pin 4, 5, 6 & 7)	28,00
MDD95-22N1B	DIODE Module-Dual Diode; 120A/2200V; T_VJM = 150°C; Phase Leg; TO-240 AA (w/o pin 4, 5, 6 & 7)	10,00
MDI150-12A4	IGBT Module-Boost & Buck Chopper; 120A/1200V; V_CE(sat) = 2,2V; Buck; Y3-DCB	68,00
MDNA380P2200KC	DIODE Module-Dual Diode; 380A/2200V; T_VJM = 150°C; Phase Leg; Y1-CU (w/o pin 4, 5, 6 & 7)	3,00
MDO500-12N1	DIODE Module-Single Diode; 560A/1200V; T_VJM = 140°C; Single; Y1-CU (w/o pin 4, 5, 6 & 7)	9,00
MDO500-18N1	DIODE Module-Single Diode; 560A/1800V; T_VJM = 140°C; Single; Y1-CU (w/o pin 4, 5, 6 & 7)	26,00
MEA75-12DA	DIODE-FRED & HiPerFRED; 75A/1200V; T_VJM = 75°C; Common Anode; TO-240AA	11,00
MEE300-06DA	DIODE-FRED & HiPerFRED; 75A/1200V; T_VJM = 75°C; Common Anode; TO-240AA	22,00
MEE95-06DA	DIODE-FRED & HiPerFRED; 95A/600V; T_VJM = 75°C; Phase Leg; TO-240AA	8,00
MEK150-04DA	DIODE-FRED & HiPerFRED; 150A/400V; T_VJM = 100°C; Common Cathode; TO-240AA	14,00
MEK250-12DA	DIODE-FRED & HiPerFRED; 260A/1200V; T_VJM = 75°C; Common Cathode; Y4-M6	32,00
MEK350-02DA	DIODE-FRED & HiPerFRED; 356A/200V; T_VJM = 75°C; Common Cathode; Y4-M6	2,00
MEK75-12DA	DIODE-FRED & HiPerFRED; 75A/1200V; T_VJM = 75°C; Common Cathode; TO-240AA	45,00
MID150-12A4	IGBT Module-Boost & Buck Chopper; 120A/1200V; V_CE(sat) = 2,2V; Boost; Y3-DCB	26,00
MID300-12A4	IGBT Module-Boost & Buck Chopper; 220A/1200V; V_CE(sat) = 2,2V; Boost; Y3-DCB	12,00
MIXA100W1200TED	IGBT Module-1200V XPT Six Pack; 84A/1200V; V_CE(sat) = 1,8V; Six Pack; E2-Pack	5,00
MIXA80W1200TED	IGBT Module-1200V XPT Six Pack; 84A/1200V; V_CE(sat) = 1,8V; Six Pack; E2-Pack	6,00
MP2060-0,005-5%	MP2060-0,005-5%	303,00
MP808-0,50-20%	MP808-0,50-20%	121,00
MP808-560-1%	MP808-560-1%	30,00
MP820-2,5K-1%	MP820-2,5K-1%	80,00
MP821-0,33-1%	MP821-0,33-1%	72,00
MP825-40,0-5%	MP825-40,0-5%	4,00
MP825-400,0-1%	MP825-400,0-1%	15,00
MP850-10,0-1%	MP850-10,0-1%	40,00
MP850-300,0-1%	MP850-300,0-1%	4,00
MP850-5,0-1%	MP850-5,0-1%	50,00
MP915-0,020-5%	MP915-0,020-5%	73,00
MP915-2,5-1%	MP915-2,5-1%	294,00

MP915-560.0-1%	MP915-560.0-1%	250,00
MP915-68.0-1%	MP915-68.0-1%	50,00
MP915-75.0-1%	MP915-75.0-1%	200,00
MP915-8,00-1%	MP915-8,00-1%	100,00
MP916-0,010-5%	MP916-0,010-5%	24,00
MP925-15,0K-1%	MP925-15,0K-1%	200,00
MP925-50,0K-1%	MP925-50,0K-1%	100,00
MP930-0,020-5%	MP930-0,020-5%	263,00
MP930-0,05-1%	MP930-0,05-1%	28,00
MP930-0,10-1%	MP930-0,10-1%	231,00
MP930-1,00-1%	MP930-1,00-1%	104,00
MP930-12,0-1%	MP930-12,0-1%	50,00
MS315-1,00K-1%	MS315-1,00K-1%	8,00
MUBW35-12A7	IGBT Module-CBI Config.; 35A/1200V; V_CE(sat) = 2,6V; CBI; E2-Pack	6,00
MWI75-12A8	IGBT Module-Six-Pack Config.; 85A/1200V; V_CE(sat) = 2,2V; Six Pack; E3-Pack	8,00
R0964LC12E	Distributed Gate Thyristors, 964A/1200V, Single, W10, Capsule Type	4,00
R1448NC20M	Distributed Gate Thyristors, 1448A/2000V, Single, W11, Capsule Type	3,00
RM400HA-24S	DIODE Modul, RM400HA-24S, 400A/1200V, H-Series, 1in1	2,00
RM60DZ-2H	1st Gen., Diode Module, 60A/1600V, Rectifier diodes, Dual, STD Type-N/A	3,00
SR10-0,10-1%	SR10-0,10-1%	50,00
UGB3132AD	RECTIFIE BRIDGES-1 & 3 Phase HV Rectifier; 1,3A/4800V; T_VJM = 150°C; 3-Phase Bridge; UGB 1~	22,00
UGE3126AY4	RECTIFIE BRIDGES-1 & 3 Phase HV Rectifier; 0,8A/24000V; T_VJM = 150°C; Single; UGE-single	49,00
VBE20-20NO1	RECTIFIE BRIDGES-1-Phase Rectifier with FRD; 20A/2000V; T_VJM = 150°C; 1-Phase B2U; V1-A-Pack	10,00
VBO105-12NO7	RECTIFIE BRIDGES-1-Phase Rectifier; 100A/1200V; T_VJM = 150°C; 1-Phase B2U; PWS-C	4,00
VBO13-12AO2	RECTIFIE BRIDGES-1~ Phase Rectifier; 18A/1200V; T_VJM = 150°C; 1-Phase B2U; FO-A	13,00
VBO50-18NO7	RECTIFIE BRIDGES-1-Phase Rectifier; 45A/1800V; T_VJM = 150°C; 1-Phase B2U; PWS-A	5,00
VBO68-16NO7	RECTIFIE BRIDGES-1-Phase Rectifier; 70A/1600V; T_VJM = 150°C; 1-Phase B2U; ECO-PAC 1	25,00
VBO72-16NO7	RECTIFIE BRIDGES-1-Phase Rectifier; 70A/1600V; T_VJM = 150°C; 1-Phase B2U; PWS-D	40,00
VGO36-16io7	RECTIFIE BRIDGES-1-Phase Half & Full Controlled; 36A/1600V; T_VJM = 125°C; 1-Phase B2HZ; ECO-PAC 1	17,00
VHF36-16io5	RECTIFIE BRIDGES-1-Phase Half & Full Controlled; 36A/1600V; T_VJM = 125°C; 1-Phase B2HKF; FO-F-A	2,00
VHFD16-08io1	RECTIFIE BRIDGES-1-Phase Half & Full Controlled; 16A/800V; T_VJM = 125°C; 1-Phase B2HKF; V1-A-Pack	9,00
VMK165-007T	MOSFET Module-Dual Switch; 165A/70V; R_DS(on) = 7Ω; VMK/FMK; TO-240 AA (+ Kelvin contact)	72,00
VMM300-03F	MOSFET Module-Phase-Leg; 290A/300V; R_DS(on) = 8,6Ω; Phase Leg; Y3-DCB	5,00
VMO1600-02P	MOSFET Module-Single Switch; 1900A/200V; R_DS(on) = 1,7Ω; Single; Y3-DCB	20,00
VMO650-01F	MOSFET Module-Single Switch; 690A/100V; R_DS(on) = 1,8Ω; Single; Y3-DCB	5,00
VUB160-16NOXT	RECTIFIE BRIDGES-3~ Phase Rectifier; 75A/1600V; T_VJM = -°C; 3-Phase Bridge; V1-A-Pack	16,00
VUB71-12NOXT	RECTIFIE BRIDGES-3~ Phase Rectifier; 75A/1600V; T_VJM = -°C; 3-Phase Bridge; V1-A-Pack	12,00
VUB72-16NOXT	RECTIFIE BRIDGES-3~ Phase Rectifier; 75A/1600V; T_VJM = -°C; 3-Phase Bridge; V1-A-Pack	10,00
VUC36-16NO2	VUC36-16NO2	4,00
VUM33-05N	RECTIFIE BRIDGES-1~ PFC (1~ Bridge + MOSFET Boost); 47A/500V; T_VJM = -°C; 1-Phase Bridge; V1-B-Pack	4,00
VUO120-16NO2T	RECTIFIE BRIDGES-3-Phase Rectifier; 180A/1600V; T_VJM = 150°C; 3-Phase B6U; V2-Pack	6,00
VUO190-16NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 240A/1800V; T_VJM = 150°C; 3-Phase B6U; PWS-E	2,00
VUO192-16NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 240A/1800V; T_VJM = 150°C; 3-Phase B6U; PWS-E	19,00
VUO110-12NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 240A/1800V; T_VJM = 150°C; 3-Phase B6U; PWS-E	1,00
VUO190-18NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 240A/1800V; T_VJM = 150°C; 3-Phase B6U; PWS-E	9,00

VUO16-18NO1	RECTIFIE BRIDGES-3-Phase Rectifier; 240A/1800V; T_VJM = 150°C; 3-Phase B6U; PWS-E	2,00
VUO22-16NO1	RECTIFIE BRIDGES-3-Phase Rectifier; 30A/1600V; T_VJM = 150°C; 3-Phase B6U; V1-A-Pack	8,00
VUO30-18NO3	RECTIFIE BRIDGES-3-Phase Rectifier; 45A/1800V; T_VJM = 150°C; 3-Phase B6U; FO-F-B	20,00
VUO34-18NO1	RECTIFIE BRIDGES-3-Phase Rectifier; 45A/1800V; T_VJM = 150°C; 3-Phase B6U; V1-A-Pack	11,00
VUO50-08NO3	RECTIFIE BRIDGES-3-Phase Rectifier; 60A/800V; T_VJM = 150°C; 3-Phase B6U; FO-F-B	5,00
VUO52-16NO1	RECTIFIE BRIDGES-3-Phase Rectifier; 60A/1600V; T_VJM = 150°C; 3-Phase B6U; V1-A-Pack	914,00
VUO52-20NO1	RECTIFIE BRIDGES-3-Phase Rectifier; 60A/2000V; T_VJM = 150°C; 3-Phase B6U; V1-A-Pack	7,00
VUO55-12NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 60A/1200V; T_VJM = 150°C; 3-Phase B6U; PWS-B	22,00
VUO60-12NO3	RECTIFIE BRIDGES-3-Phase Rectifier; 75A/1200V; T_VJM = 150°C; 3-Phase B6U; FO-F-B	6,00
VUO64-16NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 60A/1600V; T_VJM = 150°C; 3-Phase B6U; PWS-D Flat	4,00
VUO68-12NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 70A/1200V; T_VJM = 150°C; 3-Phase B6U; ECO-PAC 1	9,00
VUO68-16NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 70A/1600V; T_VJM = 150°C; 3-Phase B6U; ECO-PAC 1	27,00
VUO98-16NO7	RECTIFIE BRIDGES-3-Phase Rectifier; 105A/1600V; T_VJM = 150°C; 3-Phase B6U; ECO-PAC 2	25,00
VVZB120-12io2	VVZB120-12io2	3,00
VWM200-01P	VWM200-01P	5,00
VWM270-0075X2	VWM270-0075X2	4,00
W0438SC240	Rectifier Diode, 438A/2400V, Single S, W24, Stud Type	4,00
W2115MC600 CAB	Rectifier Diode, 2122A/6000V, Single, W54, Capsule Type	6,00